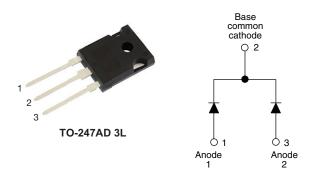
VS-C4PH6006L-N3

Vishay Semiconductors



Hyperfast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 30 A					
V _R	600 V					
V _F at I _F	1.37 V					
t _{rr} typ.	see Recovery table					
T _J max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration Common cathode						

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{BBM} and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Designed and gualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_F, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V _R		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 122 °C	30	٨			
Non-repetitive peak surge current, per leg	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
		I _F = 30 A	-	1.65	2			
Forward voltage		I _F = 60 A	-	1.95	-	V		
	VF	I _F = 30 A, T _J = 125 °C	-	1.44	-			
	VF	I _F = 60 A, T _J = 125 °C	-	1.78	-			
		I _F = 30 A, T _J = 150 °C	-	1.37	1.6			
		I _F = 60 A, T _J = 150 °C	-	1.68	-			
Payaraa laakaga aurrant		$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 600 V	-	18.3	-	pF		



RoHS



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time	+	$T_J = 25 \ ^\circ C$		-	55	-	ns		
Reverse recovery time	t _{rr}	T _J = 125 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 400 V	-	75	-	115		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	13	-	Α		
Feak recovery current		T _J = 125 °C		-	23	-	A		
Reverse recovery charge C	Q _{rr}	T _J = 25 °C		-	500	-	20		
neverse recovery charge	Qrr	T _J = 125 °C		-	1250	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS		TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	-	1			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.4	-			
Weight			-	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	C4PH6006L					

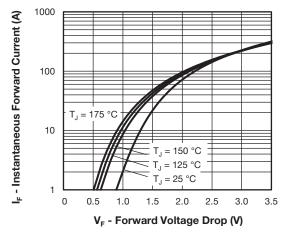


Fig. 1 - Typical Forward Voltage Drop Characteristics

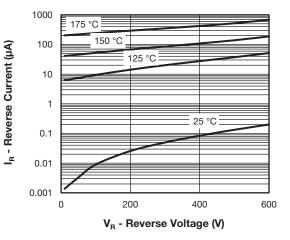


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



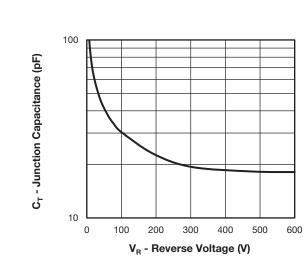


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

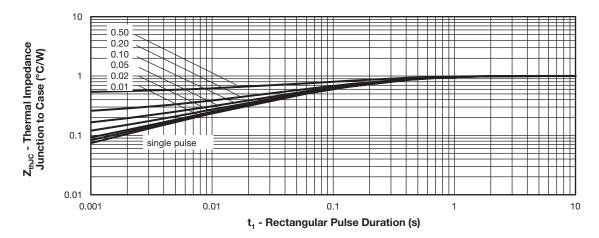
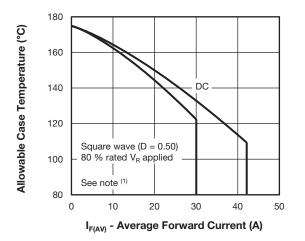
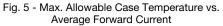


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

⁽¹⁾ Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{Fig.5}) \\ \mathsf{P}_{\mathsf{d}\mathsf{R}\mathsf{EV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R}1} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$

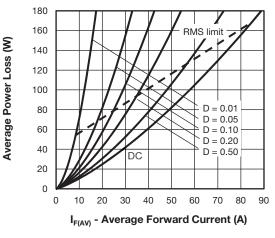


Fig. 6 - Forward Power Loss Characteristics

Revision: 19-Feb-2019

3

Document Number: 95949

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VS-C4PH6006L-N3

Vishay Semiconductors

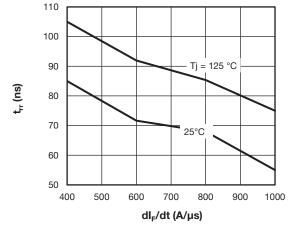


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

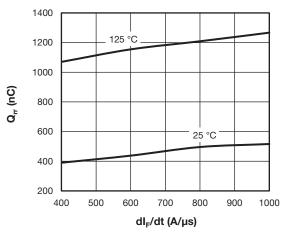


Fig. 8 - Typical Stored Charge vs. dl_F/dt

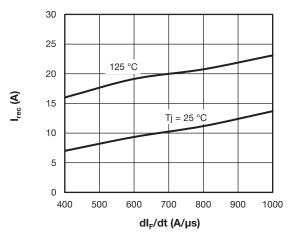


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt





ORDERING INFORMATION TABLE

Device code	VS-	С	4	Р	Н	60	06	L	-N3
	1	2	3	4	5	6	7	8	9
	 Vishay Semiconductors product Circuit configuration: 								
		C = common cathode							
		4 - P = TO-247 package							
	5 -		cess typ	be: ist recov	/erv				
	6 -			ng (60 =	-				
	8 -	8 - L = long lead							
	9 -			ntal digit: en-free,		complia	nt, and	totally l	ead (Pb

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-C4PH6006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95626					
Part marking information	www.vishay.com/doc?95007					



TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	0.215 BSC	
ØК	0.2	0.254		010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

 Revision: 06-Mar-2020
 1
 Document Number: 95626

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